PNP -5A -60V Middle Power Transistor

Parameter	Value
V_{CEO}	-60V
I _C	-5A

Features

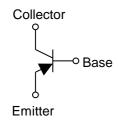
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SC5103
- 3) Low V_{CE(sat)}

$$V_{CE(sat)}$$
= $-0.3V(Max.)$ (I_C/I_B = $-3A/-0.15A$)

$$V_{CE(sat)} = -0.5V(Max.) (I_C/I_B = -4A / -0.2A)$$

4) Lead Free/RoHS Compliant.

●Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SA1952	CPT3	6595	TL	330	16	2,500	A1952

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V _{CBO}	-100	V
Collector-emitter voltage		V _{CEO}	-60	V
Emitter-base voltage		V_{EBO}	-5	V
	DC	I _C	-5	Α
Collector current	Pulsed	I _{CP}	-10	Α
Power dissipation		P_{D}^{*1}	1	W
		P _D *2	10	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

^{*1} Mounted on a substrate

^{*2} Tc=25°C

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	$I_C = -1mA$	-60	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_C = -50\mu A$	-100	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -50\mu A$	-5	-	ı	V
Collector cut-off current	I _{CBO}	V _{CB} = -100V	ı	ı	-10	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = -5V$	ı	ı	-10	μА
Collector-emitter	\/ *1	$I_C = -3A$, $I_B = -0.15A$ $I_C = -4A$, $I_B = -0.2A$	ı	ı	-0.3	V
saturation voltage	V CE(sat)	$I_C = -4A, I_B = -0.2A$	ı	ı	-0.5	V
Base-emitter	V _{BE(sat)} *1	$I_C = -3A$, $I_B = -0.15A$ $I_C = -4A$, $I_B = -0.2A$	ı	ı	-1.2	V
saturation voltage	V BE(sat)	$I_{C} = -4A, I_{B} = -0.2A$	ı	ı	-1.5	V
DC current gain	h _{FE} 1*1	$V_{CE} = -2V, I_{C} = -1A$	120	ı	270	-
DO current gain	h _{FE} 2*1	$V_{CE} = -2V, I_{C} = -3A$	40	ı	ı	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 0.5A$ f=30MH _z	-	80	ı	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V$, $I_E = 0A$ f = 1MHz	ı	130	ı	pF
Turn-on time	t _{on} *2	I _C = -3A	-	-	0.3	μS
Storage time	t _{stg} *2	I _{B1} = -0.15A I _{B2} =0.15A	-	-	1.5	μS
Fall time	t _f *2	V _{CC} ≃ −30V	-	-	0.3	μs

^{*1} Plused

●h_{FE} rank categories Rank

	Rank	Q								
	h_{FE}	120 to 2	70							
1	V _{IN}		l _{B1}	R _L =10Ω			BASE CURENT WAVEFORM			l _{B2}
_	→ Pw k—	·-/\/	←	↑ lc	<u></u>	/ _{cc} ≃ −30V			 	 l _{B1} /
		Pw ≃ 50μs DUTY CYCLE ≤ 1%	\[\begin{align*}	177	,,,		90%	→ ton ←	← t _{eta} → t	<u> </u>
			S				COLLECTOR CURREL WAVEFORM	и		lc
							10%	-	<u> </u>	 k

^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

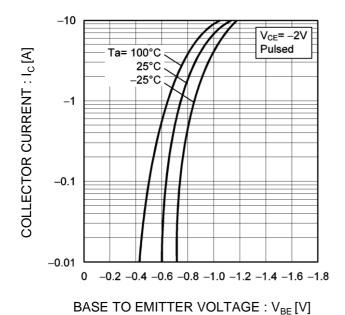
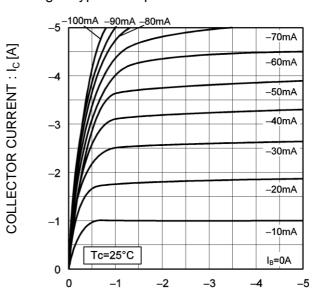


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current (I)

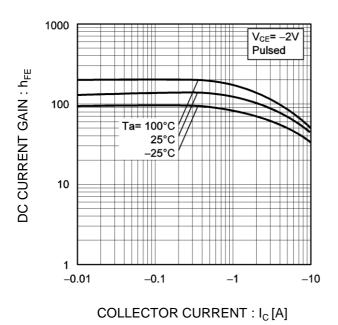
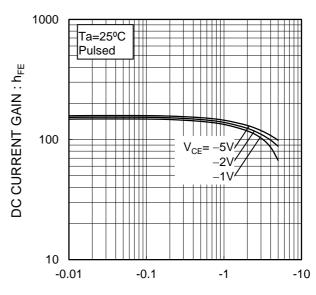


Fig.4 DC Current Gain vs. Collector Current (II)



COLLECTOR CURRENT: Ic [A]

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

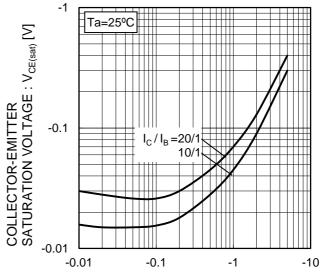
vs. Collector Current (I)

-0.1

Ta= 100°C
25°C
-25°C
-25°C

-0.01

Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)



COLLECTOR CURRENT: Ic [A]

COLLECTOR CURRENT : I_C[A]

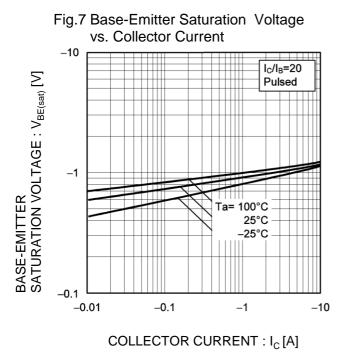
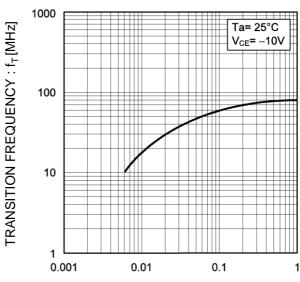


Fig.8 Gain Bandwidth Product vs. Emitter Current



EMITTER CURRENT :I_E [A]

●Electrical characteristic curves(Ta = 25°C)

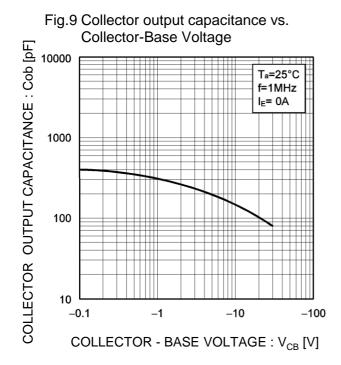
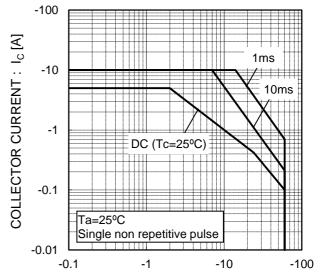
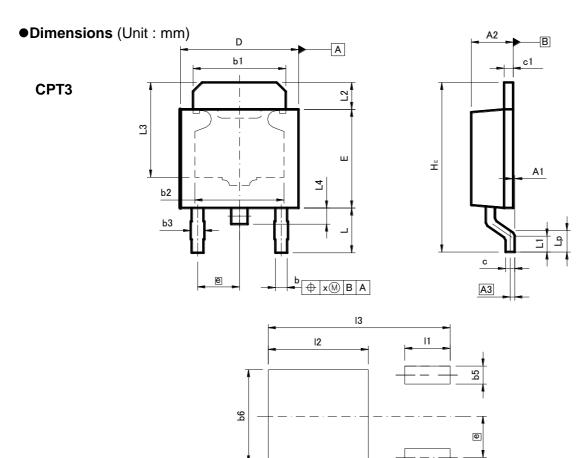


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\left[V\right]$



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.:	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2		00	0.1	97
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
е	2.3	30	0.0	91
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.	5.30		09
L4	0.9	90	0.0	35
Lp	1.00	1.60	0.039	0.063
Х	_	0.25	_	0.010

DIM	MILIMI	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b5	_	1.00	-	0.04
b6	_	5.20	1	0.205
I1	_	2.50	-	0.098
12	_	5.50	_	0.217
13	-	10.00	-	0.394

Dimension in mm / inches

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